



A Product Line of Diodes Incorporated



FMMT491

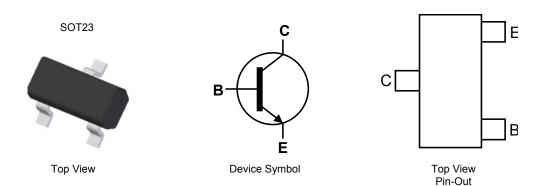
60V NPN MEDIUM POWER TRANSISTOR IN SOT23

Feature

- BV_{CEO} > 60V
- I_C = 1A Continuous Collector Current
- I_{CM} = 2A Peak Pulse Current
- R_{CE(sat)} = 195mΩ for a low equivalent On-Resistance
- 500mW Power Dissipation
- h_{FE} characterised up to 2A for high current gain hold up
- Complementary PNP Type: FMMT591
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (approximate)



Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT491TA | AEC-Q101 | 491 | 7 | 8 | 3,000 |
| FMMT491TC | AEC-Q101 | 491 | 13 | 8 | 10,000 |

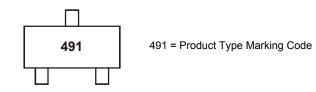
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information







FMMT491

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 80 | V |
| Collector-Emitter Voltage | V _{CEO} | 60 | V |
| Emitter-Base Voltage | V _{EBO} | 7 | V |
| Continuous Collector Current | Ι _C | 1 | А |
| Peak Pulse Current | I _{CM} | 2 | А |
| Base Current | IB | 200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|----------------------------------|-------------|------|
| Power Dissipation (Note 5) | PD | 500 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{	ext{	heta}}JA$ | 250 | °C/W |
| Thermal Resistance, Junction to Lead (Note 6) | R _{θJL} | 197 | °C/W |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -55 to +150 | ٥C |

ESD Ratings (Note 7)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

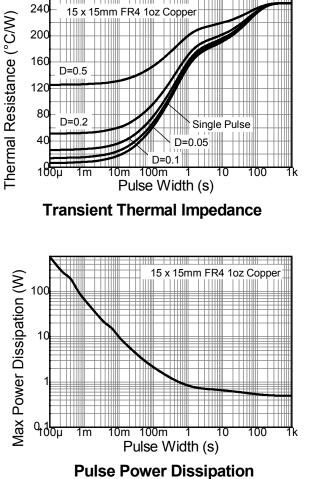
6. Thermal resistance from junction to solder-point (at the end of the collector lead).

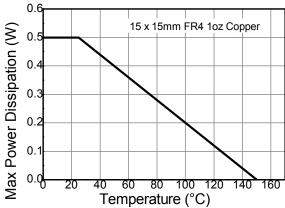
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information





Derating Curve





FMMT491

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

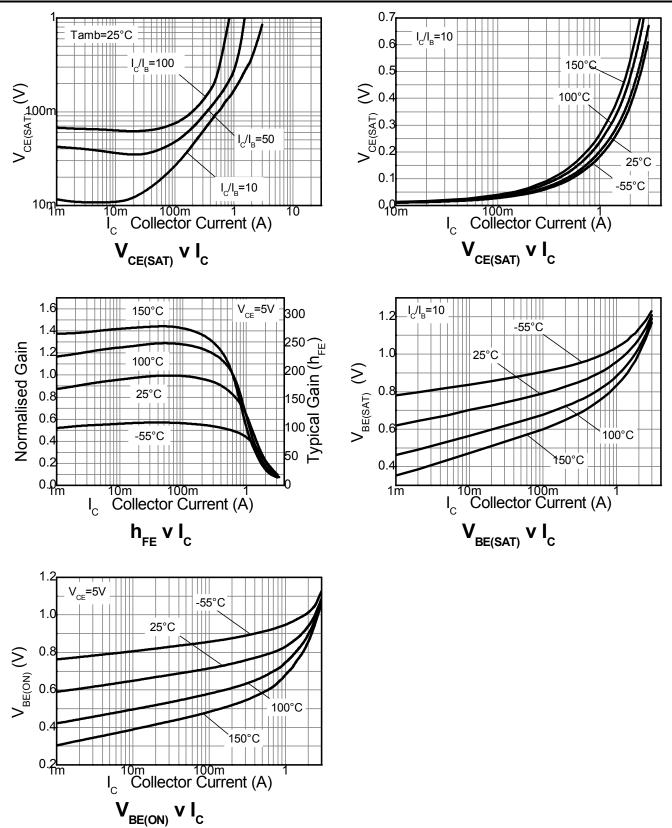
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|----------------------|-----|-----|------|------|---|
| Collector-Base Breakdown Voltage | BV _{CBO} | 80 | _ | — | V | I _C = 100μA |
| Collector-Emitter Breakdown Voltage (Note 8) | BV _{CEO} | 60 | _ | — | V | I _C = 10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 7 | 8.1 | — | V | I _E = 100μA |
| Collector Cutoff Current | I _{CBO} | — | <1 | 100 | nA | V _{CB} = 60V |
| Emitter Cutoff Current | I _{EBO} | _ | <1 | 100 | nA | V _{EB} = 5.6V |
| Collector Emitter Cutoff Current | I _{CES} | — | <1 | 100 | nA | V _{CE} = 60V, V _{CES} = 60V |
| | | 100 | 140 | — | | I _C = 1mA, V _{CE} = 5V |
| Chatia Ferruard Current Transfer Datia (Mate 9) | h _{FE} | 100 | 150 | 300 | _ | I _C = 500mA, V _{CE} = 5V |
| Static Forward Current Transfer Ratio (Note 8) | | 80 | 120 | — | | I _C = 1A, V _{CE} = 5V |
| | | 30 | 40 | — | | I _C = 2A, V _{CE} = 5V |
| Collector Emitter Seturation Voltage (Note 9) | V _{CE(sat)} | _ | 100 | 150 | v | I _C = 500mA, I _B = 50mA |
| Collector-Emitter Saturation Voltage (Note 8) | | _ | 160 | 250 | v | I _C = 1A, I _B = 100mA |
| Base-Emitter Turn-On Voltage(Note 8) | V _{BE(on)} | _ | 830 | 1000 | mV | I _C = 1A, V _{CE} = 5V |
| Base-Emitter Saturation Voltage(Note 8) | V _{BE(sat)} | — | 965 | 1100 | mV | I _C = 1A, I _B = 100mA |
| Output Capacitance | Cobo | — | _ | 10 | pF | V _{CB} = 10V, f = 1MHz |
| Transition Frequency | f _T | 150 | _ | _ | MHz | V _{CE} = 10V, I _C = 50mA, f = 100MHz |

8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%. Note:





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

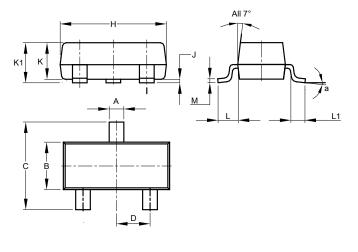






Package Outline Dimensions

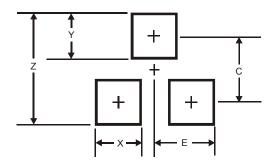
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| SOT23 | | | | | |
|----------------------|-------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.37 | 0.51 | 0.40 | | |
| В | 1.20 | 1.40 | 1.30 | | |
| С | 2.30 | 2.50 | 2.40 | | |
| D | 0.89 | 1.03 | 0.915 | | |
| F | 0.45 | 0.60 | 0.535 | | |
| G | 1.78 | 2.05 | 1.83 | | |
| Н | 2.80 | 3.00 | 2.90 | | |
| J | 0.013 | 0.10 | 0.05 | | |
| Κ | 0.890 | 1.00 | 0.975 | | |
| K1 | 0.903 | 1.10 | 1.025 | | |
| L | 0.45 | 0.61 | 0.55 | | |
| L1 | 0.25 | 0.55 | 0.40 | | |
| М | 0.085 | 0.150 | 0.110 | | |
| а | 8° | | | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| Z | 2.9 | | |
| Х | 0.8 | | |
| Y | 0.9 | | |
| С | 2.0 | | |
| E | 1.35 | | |





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